

Thermionic cathode-based injector R&D at Argonne National Laboratory

Ryan R. Lindberg

Compact x-ray FELs using high-brightness beams workshop

August 5, 2010

Berkeley, CA

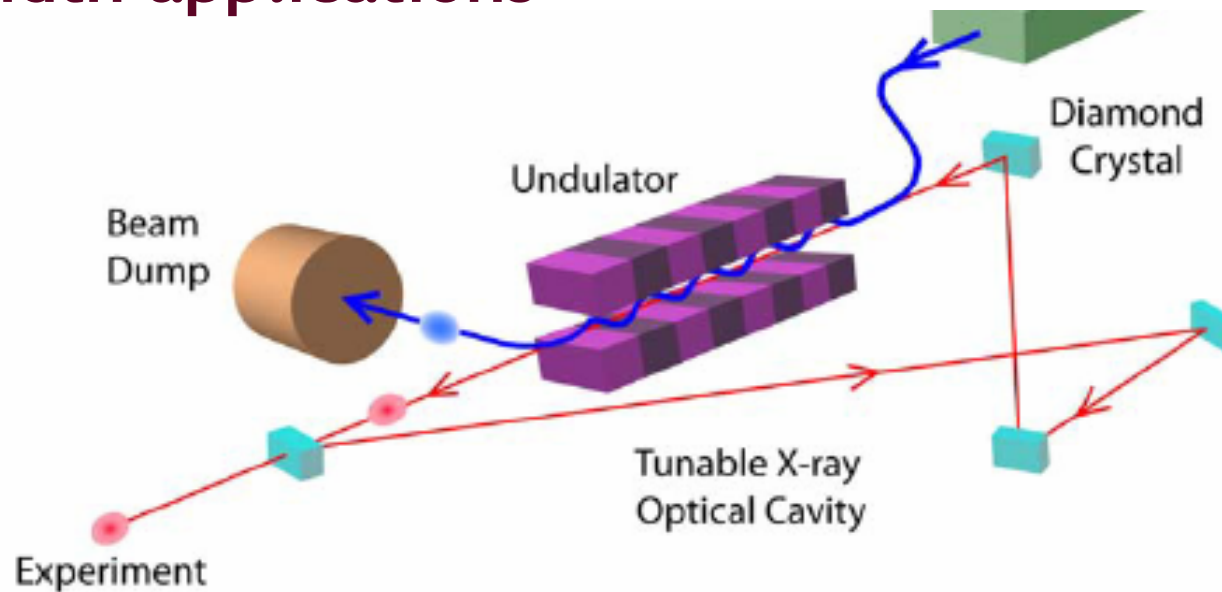
Acknowledgements

- ANL

M. Borland, X. Dong, K. Harkay, K.-J. Kim, A. Nassiri, P.N. Ostroumov, J. Power, N. Sereno, ...

- P. Piot (NIU), T. Shintake (SPring-8), LBNL CBP, ...

Motivation: an x-ray FEL oscillator for ultra-low bandwidth applications



An x-ray pulse is stored in a cavity formed by diamond Bragg crystals
→ low pass gain and spectral cleaning over many passes

Fourier transform limited pulses: $\Delta\omega/\omega \sim 10^{-7}$ → $\hbar\Delta\omega \sim 1$ meV

10^9 photons/pulse with brightness 10^{32} photons/s/mm²/mrad²/0.1%BW

1. R. Coella and A. Luccio, Optics Comm. **50**, 41 (1984).
2. K.-J. Kim, Y. Shvyd'ko, and S. Reiche, Phys. Rev. Lett. **100**, 244802 (2008)

Injector requirements for an x-ray FEL oscillator

- High beam quality
 - Normalized emittance < 0.2 mm-mrad (rms)
 - Energy spread $\Delta E/E < 2 \times 10^{-4}$ (rms)
- “Long” bunch length ~ 0.1 to 1 ps (rms)
 - Fourier transform limited electron beam bandwidth $<$ Bragg crystal bandwidth $\Delta\omega/\omega \sim 10^{-6}$ to 10^{-7}
- Low charge < 50 pC: peak current between 10 and 100 A
- Bunch repetition rate 1 MHz (to 10 MHz for multiple XFELs)
 - Rep rate matches round trip time of x-rays in cavity



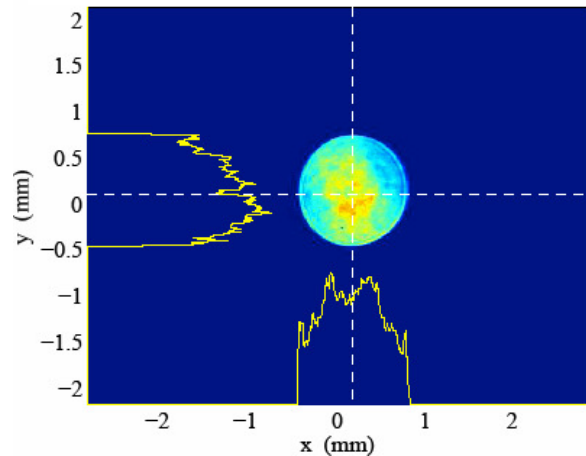
Electron gun technologies in use and under development

- The LCLS photoinjector produces low-charge beams of sufficient quality ($\epsilon_{x,n} = 0.14$ @ 20 pC charge), but the repetition rate ~ 120 Hz
- The PITZ gun may be suitable for a *pulsed* x-ray FEL oscillator
 - $\epsilon_{x,n} = 0.3-0.4$ mm-mrad @ 100 pC charge, $f_b = 1$ MHz for 800 μ s, $f_{\text{macro}} = 10$ Hz
- ERL-type guns may satisfy XFEL requirements
 - Cornell: $\epsilon_{x,n} = 0.2$ mm-mrad @ 20 pC charge (but calls for 750 kV DC voltage)
 - KEK-JAEA: $\epsilon_{x,n} = 0.1$ mm-mrad @ 6 pC charge (using 600 kV DC voltage)
- The LBNL 200 MHz gun design (presented earlier) could be configured to satisfy the XFEL requirements
- RIKEN/SPring-8 thermionic pulsed DC
 - 500 kV @ 60 Hz, $\epsilon_{x,n} = 0.6$ mm-mrad with a 3mm cathode diameter
- We discuss an alternative approach drawing on these ideas/designs

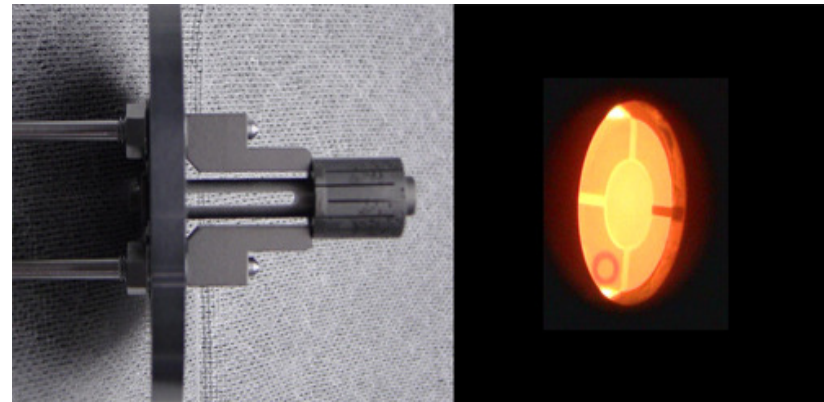


Photocathode or thermionic cathode?

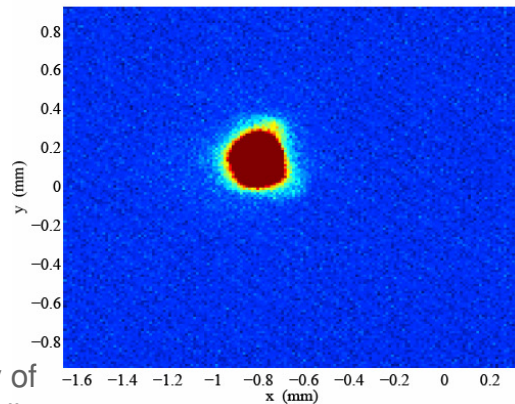
Intensity distribution of a "good" laser spot



SCSS CeB₆ thermionic cathode

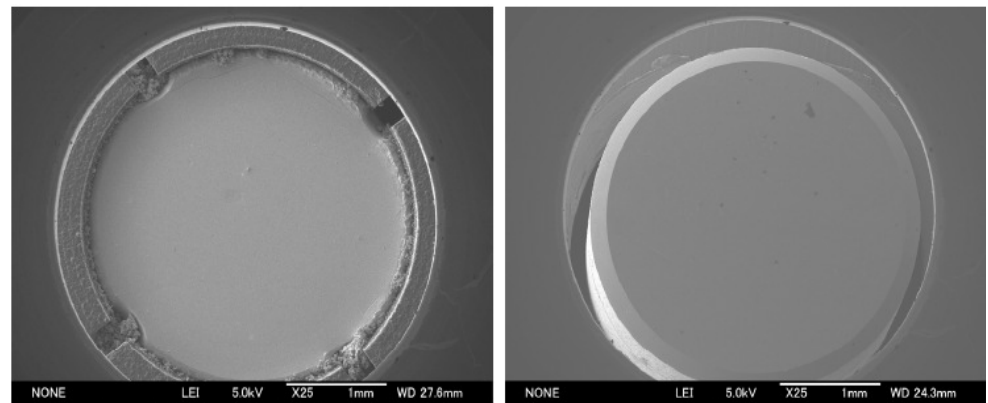


Electron distribution from the photocathode



Courtesy of
D. Dowell

CeB₆ cathode after 20,000 hrs. of operation (left) and new (right)



For low intensity and ultra-low emittance, thermionic cathodes are an option capable of long-term, stable operation

Courtesy of
T. Shintake



A high repetition rate thermionic injector

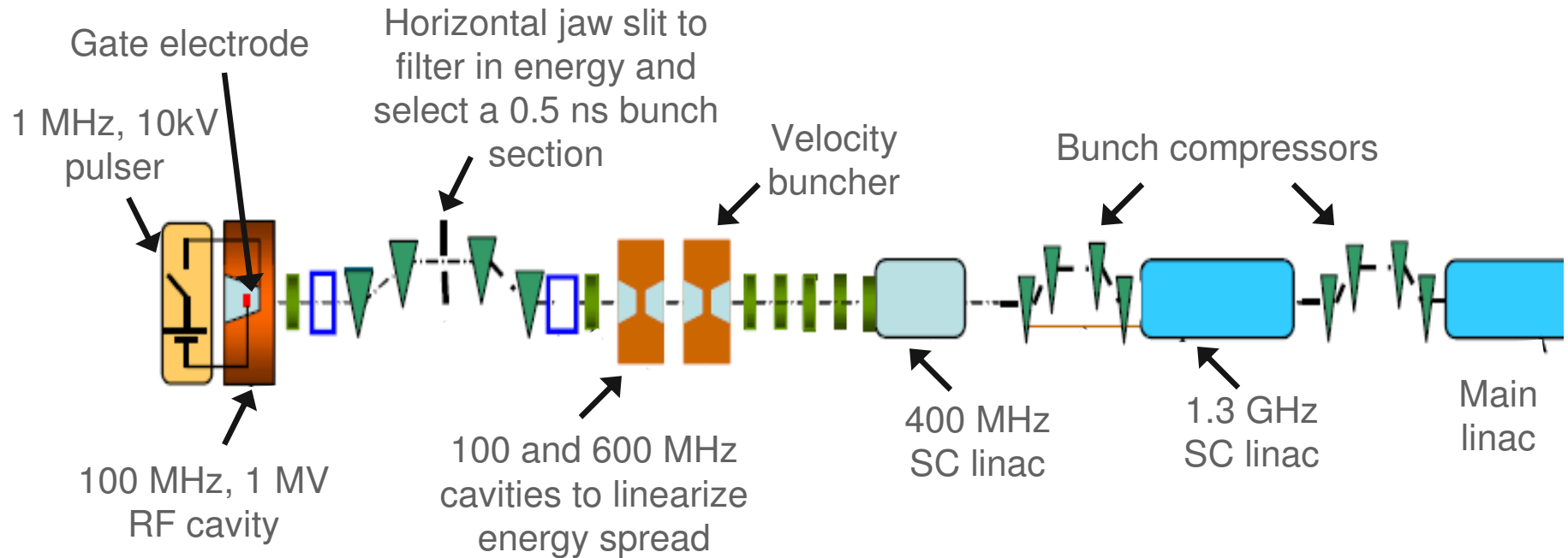
- Current paradigm of injector design is based on the laser-driven rf photocathode
 - Demonstrated success for **high-current, low emittance** beams
- XFEL requirements are different:
 - Low-current, ultra-low emittance** beams at a **constant MHz repetition rate**
- An alternative approach uses a thermionic cathode inside a low frequency RF cavity
 - Inspired by the success of the pulsed DC thermionic gun at SPring-8
- The injector can also be configured to produce beams suitable for ultrafast SASE (i.e., few fs pulses), although this is not our focus

3. P.N. Ostroumov, K.-J. Kim, and P. Piot, Proceedings of the LINAC-08, pp 666

4. P.N. Ostroumov, D. Capatina, K.-J. Kim, S.A. Kondrashev, B. Mustapha, and A. Nassiri, Proceedings of the 2009 Particle Accelerator Conference



Injector concept applicable to XFEL0



- 100 MHz RF scaled from the Berkeley design⁵
- Thermionic cathode inspired by SPring-8 success⁶
- High voltage, 1 MHz pulsed electrode to gate emission, eliminating need for high power beam dump and mitigating back-bombardment on the cathode

5. K. Baptiste, J. Corlett, S. Kwiatkowski, S. Lidia, J. Quiang, F. Sannibale, K. Sonnad, J. Stapes, S. Virostek, and R. Wells, Nucl. Instrum. Methods Res. A **599**, 9 (2009).

6. K. Togawa, T. Shintake, T. Inagake, K. Onoe, T. Tanaka, H. Baba, and H. Matsumoto, Phys. Rev. ST-Accel. Beams **10**, 020703 (2007).

Taming the electron beam power

- To achieve emittance goals, the effective cathode area should be ~ 10 times smaller than the cathode used at SPring-8.
- Very small cathodes may suffer in performance
 - Dominated by the etched/damaged cathode periphery
- So, we'd like to select some small transverse portion of the beam
- If we do this after accelerating by the ~1 MV in the gun, the beam power on the slits/aperture would be several kW
- To deal with this beam power, we might use

Pulsed gate electrode?

Extreme beam dump?

Laser-assisted flash heating?

???

Taming the electron beam power

- To achieve emittance goals, the effective cathode area should be ~ 10 times smaller than the cathode used at SPring-8.
- Very small cathodes may suffer in performance
 - Dominated by the etched/damaged cathode periphery
- So, we'd like to select some small transverse portion of the beam
- If we do this after accelerating by the ~1 MV in the gun, the beam power on the slits/aperture would be tens of kW
- To deal with this beam power, we might use

Pulsed gate electrode

Extreme beam dump?

Laser-assisted flash heating?

???

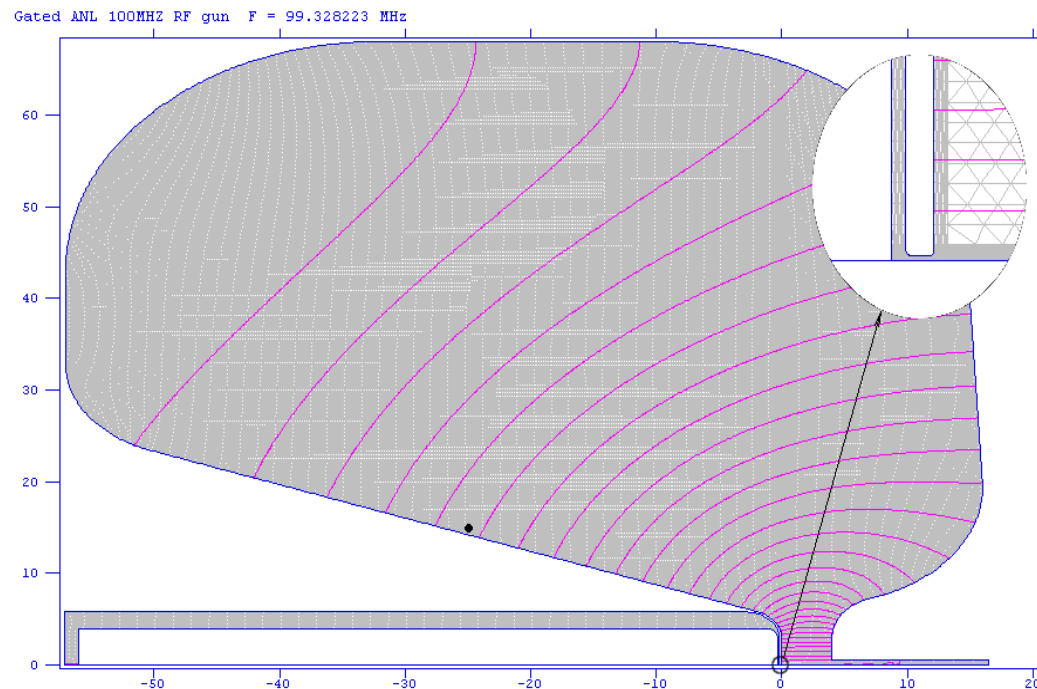
Our base-line design choice



Gating electrode

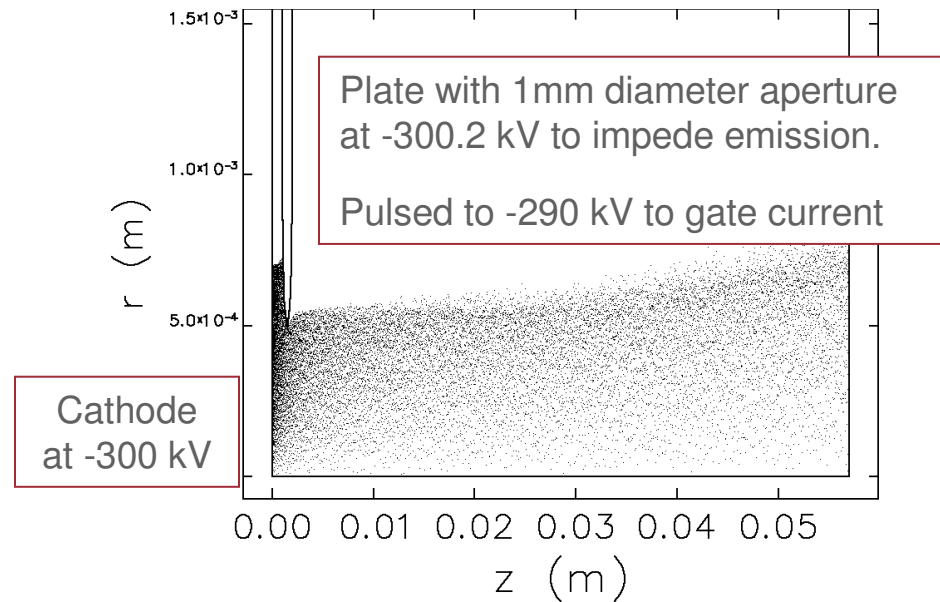
- Thin (~ 1 mm) plate with small (~ 1 mm) hole shields rf field
- The current is gated by a pulse of ~ 10 kV over ~ 5 ns
- The hole selects a small portion of the beam at low energy and a 1 MHz repetition rate, yielding low emittance at low beam power.

Calculation of the
cavity fields
including the gating
electrode using
Superfish/Poisson

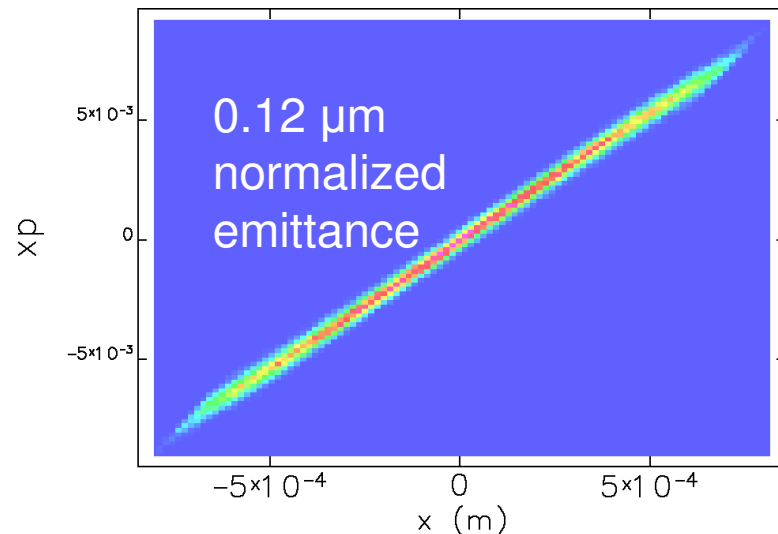
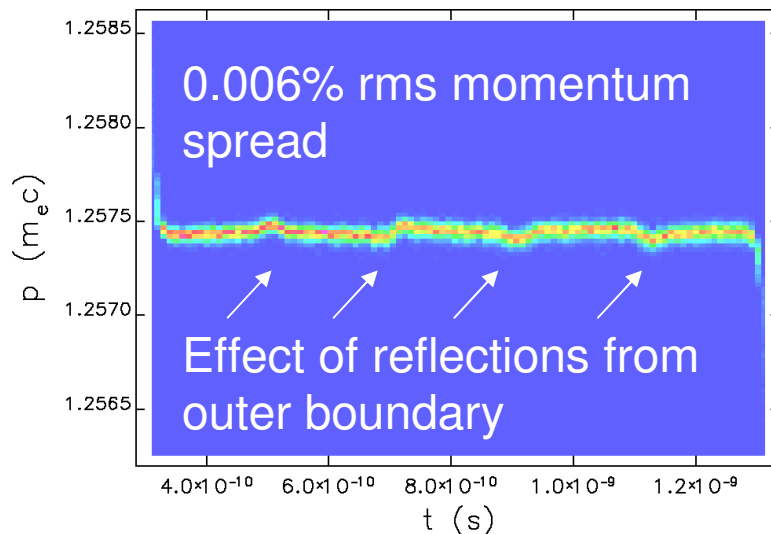


First look at a 1 MHz, 300 kV DC gated gun

- Modeled using SPIFFE⁷ with static potentials (not pulsed)
- 0.07 A measured current
- Beam quality includes thermal velocity spread (1500 K cathode)



7. M. Borland, Users guide to SPIFFE, www.aps.anl.gov



Fast switch technology

- Main commercial supplier is FID
- < 1kV, 1 MHz fast switch suitable for constant operation exists today
- A 10 kV, 3 MHz fast switch is being presently used at the Accelerator Test Facility (KEK)

Pulsed operation for a ~ millisecond every 5 Hz

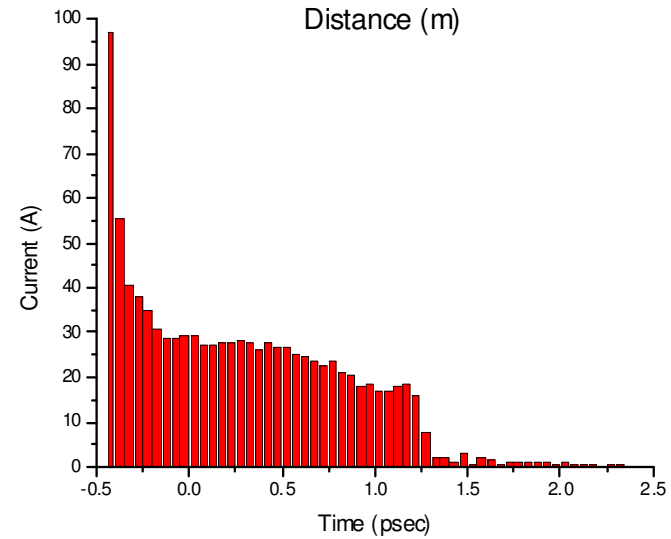
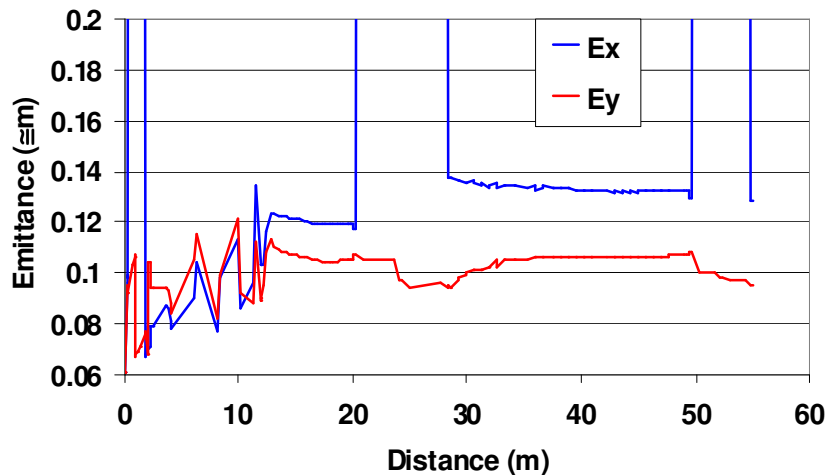
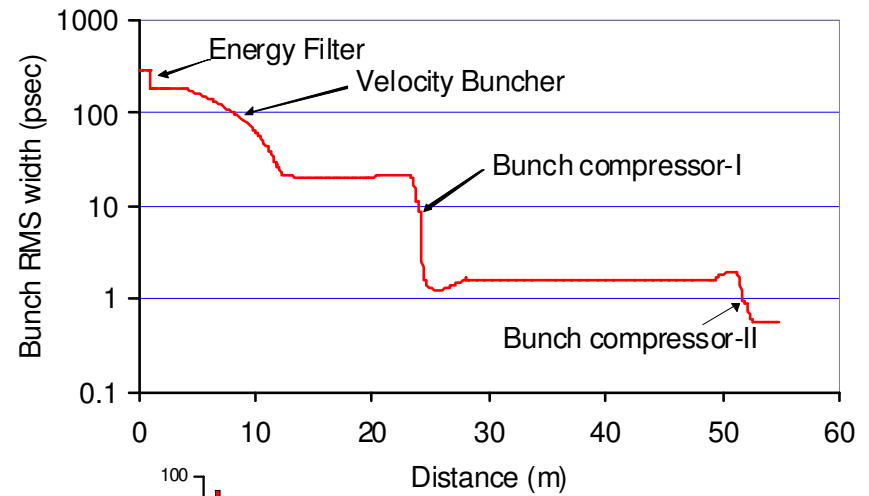
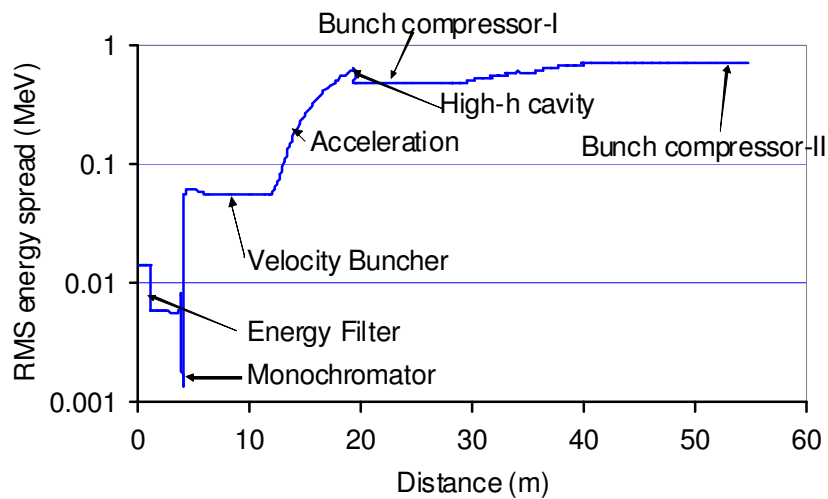
- A 10 kV, 1 MHz fast switch for constant operation is a technological challenge

FID has said it can make a suitable high voltage switch

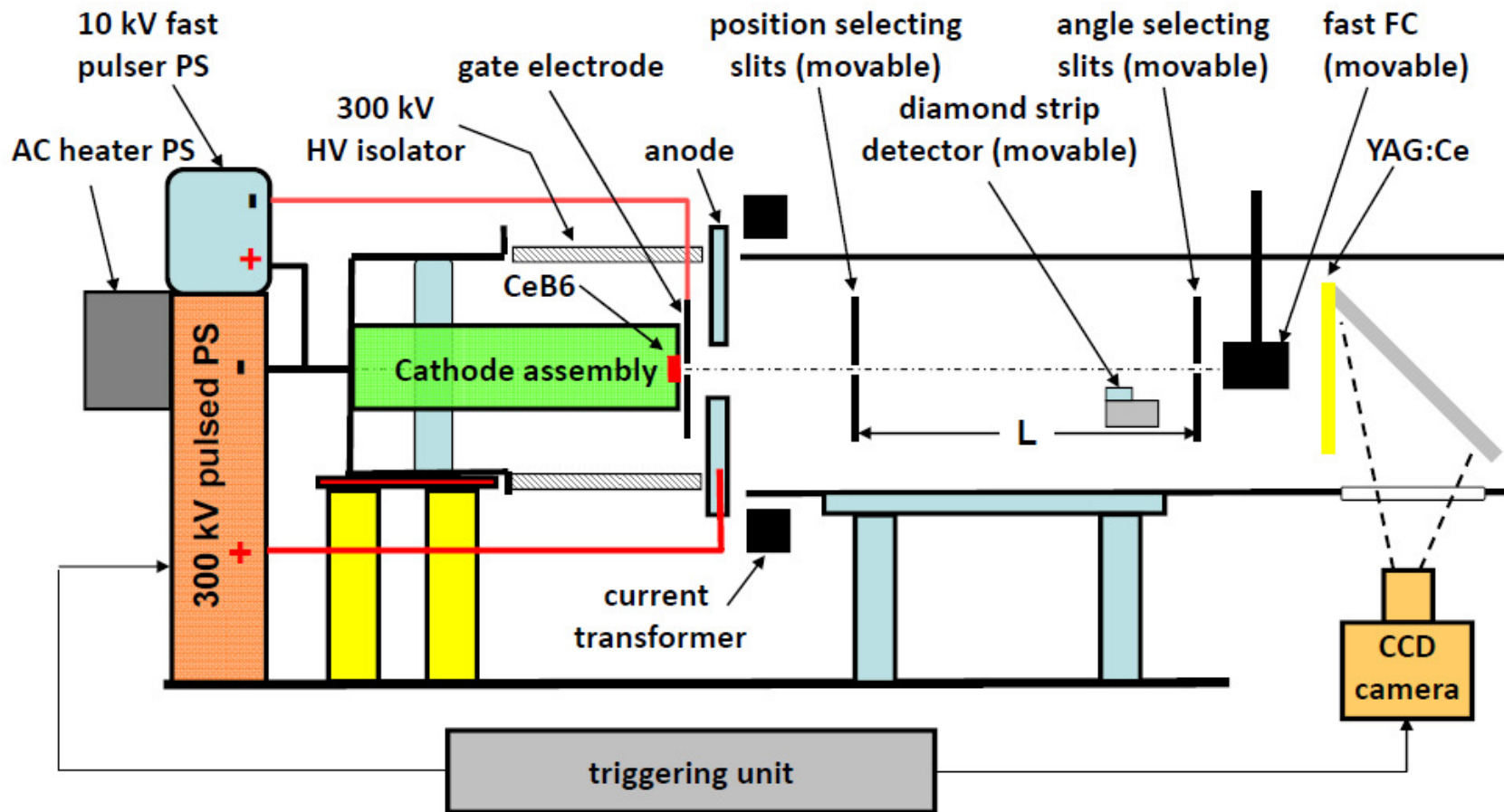
Advances in semiconductor technology
may solve this problem for us...

- These high voltage fast switches may have other applications in, e.g, beam switchyards for high repetition rate FEL facilities

3D TRACK simulation of injector performance, optimized with a genetic algorithm

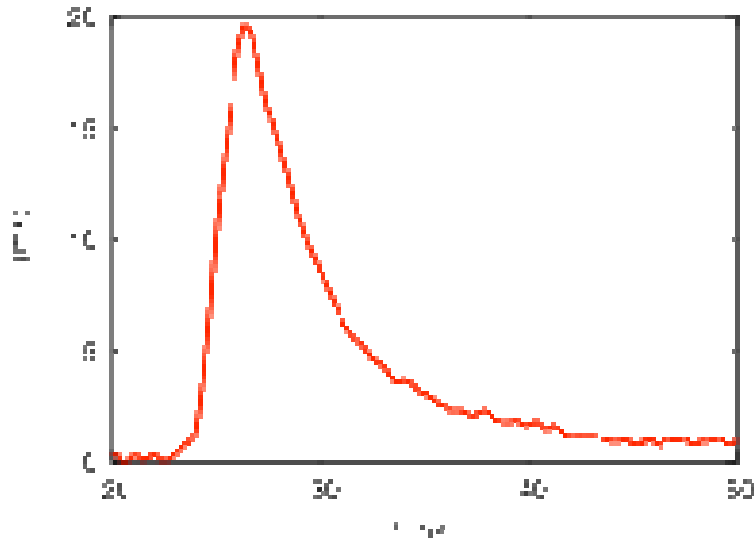


A pulsed DC gun test stand



Other possible gating schemes

- High power electron beam dump
 - One could simply remove most of the beam with an rf cosine chopper and a high-power electron beam collector (EBIS-type parameters)
 - Electron back-bombardment ameliorated with 3-pole wiggler
- Laser-assisted thermionic emission
 - Cathode is kept at a temperature below the emission threshold
 - Laser used to flash-heat the cathode over a short time for emission



Experiment at ITS facility at APS showed short pulse emission is possible with reasonable agreement to 1D theory⁸

8. N.S. Sereno, M. Borland, K. Harkay, Y. Li, and R.R. Lindberg, APS technical note in preparation (2010).

Conclusions

- XFEL requires an ultra-low emittance, low charge beam at a high repetition rate
 - Thermionic cathodes provide stable, high quality beams that appear to be well-suited for XFEL
 - Primary problems to surmount include
 - Back-bombardment on the cathode
 - Beam power to be dumped from the gun
- Both problems can be ameliorated by gating the emission at the cathode
- High voltage electrode for gating is theoretically quite attractive
 - Realizing one is challenging but probably feasible
 - Other gating mechanisms are also being investigated

